DATA SHEET

74LV4067

16-channel analog multiplexer/demultiplexer

Product specification Supersedes data of 1997 Jul 15 IC24 Data Handbook





74LV4067

FEATURES

- Optimized for low voltage applications: 1.0 to 6.0 V
- \bullet Accepts TTL input levels between $V_{CC} = 2.7 \text{ V}$ and $V_{CC} = 3.6 \text{ V}$
- Low typ "ON" resistance: 60 Ω at V_{CC} – GND = 4.5 V 90 Ω at V_{CC} – GND = 3.0 V 145 Ω at V_{CC} – GND = 2.0 V
- Typical "break before make" built in
- Output capability: non-standard
- I_{CC} category: MSI

DESCRIPTION

The 74LV4067 is a low-voltage CMOS device and is pin and function compatible with 74HC/HCT4067.

The 74LV4067 is an 16-channel analog multiplexer/demultiplexer with four address inputs (S $_{\!\scriptscriptstyle 0}$ to S $_{\!\scriptscriptstyle 3}$), an active LOW enable input ($\overline{\!\mathsf{E}}\!$), sixteen independent inputs/outputs (Y_0 to Y_{15}) and a common input/output (Z).

The 74LV4067 contains sixteen bidirectional analog switches, each with one side connected to an independent input/output (Y₀ to Y₁₅) and the other side connected to a common input/output (Z).

With $\overline{\mathsf{E}}$ LOW, one of the sixteen switches is selected (low impedance ON-state) by S_0 to S_3 . All unselected switches are in the high impedance OFF-state. With E HIGH, all switches are in the high impedance OFF-state, independent of S₀ to S₃.

The analog inputs/outputs (Y_0 to Y_{15} , and Z) can swing between V_{cc} as a positive limit and GND as a negative limit. Vcc - GND may not exceed 6.0 V.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PZH} /t _{PZL}	Turn "ON" time E to V _{OS} S _n to V _{OS}	$C_L = 15 \text{ pF}$ $R_L = 1K\Omega$ $V_{CC} = 3.3 \text{ V}$	25 27	ns
t _{PHZ} /t _{PLZ}	Turn "OFF" time E to V _{OS} S _n to V _{OS}		25 27	ns
C _I	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per switch	See Notes 1 and 2	29	pF
C _S	Maximum switch capacitance independent (Y) common (Z)		5 45	pF

NOTE:

$$\begin{split} P_D &= C_{PD} \times V_{CC}{}^2 \times f_i \ + \sum \left(C_L \times V_{CC}{}^2 \times f_o \right) \text{ where:} \\ f_i &= \text{input frequency in MHz; } C_L = \text{output load capacity in pF;} \end{split}$$

 f_0 = output frequency in MHz; \overline{C}_S = max. switch capacitance in pF; V_{CC} = supply voltage in V;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$

The condition is $V_I = GND$ to V_{CC} .

ORDERING INFORMATION

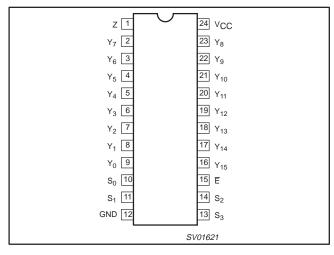
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
24-Pin Plastic DIL	–40°C to +125°C	74LV4067 N	74LV4067 N	SOT101-1
24-Pin Plastic SO	-40°C to +125°C	74LV4067 D	74LV4067 D	SOT137-1
24-Pin Plastic SSOP Type II	-40°C to +125°C	74LV4067 DB	74LV4067 DB	SOT340-1
24-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV4067 PW	74LV4067PW DH	SOT355-1

 C_{PD} is used to determine the dynamic power dissipation (P $_{D}$ in $\mu W)$

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16-channel analog multiplexer/demultiplexer

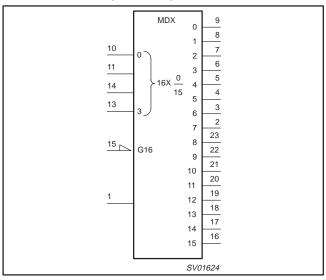
PIN CONFIGURATION



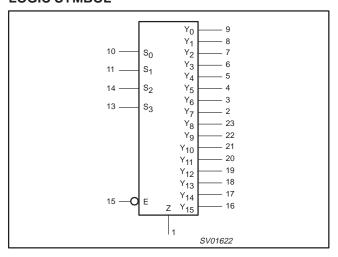
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	Z	Common input/output
9, 8, 7, 6, 5, 4, 3, 2, 23, 22, 21, 20, 19, 18, 17, 16	Y ₀ to Y ₁₅	Independent inputs/outputs
10, 11, 14, 13	S ₀ to S ₃	Select inputs
12	GND	Ground (0 V)
15	Ē	Enable input (active LOW)
24	V _{CC}	Positive supply voltage

LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL

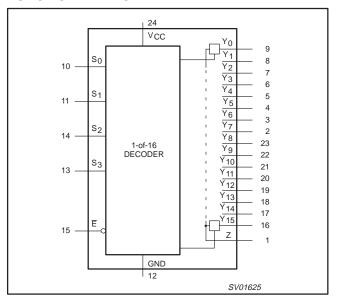


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FUNCTION TABLE

		INPUTS			CHANNEL
Ē	S ₃	S ₂	S ₁	S ₀	ON
L	L	L	L	L	$Y_0 - Z$
L	L	L	L	Н	$Y_1 - Z$
L	L	L	Н	L	$Y_2 - Z$
L	L	L	Н	Н	$Y_3 - Z$
L	L	Н	L	L	Y ₄ – Z
L	L	Н	L	Н	Y ₅ – Z
L	L	Н	Н	L	$Y_6 - Z$
L	L	Н	Н	Н	Y ₇ – Z
L	Н	L	L	L	Y ₈ – Z
L	Н	L	L	Н	Y ₉ – Z
L	Н	L	Н	L	$Y_{10} - Z$
L	Н	L	Н	Н	Y ₁₁ – Z
L	Н	Н	L	L	Y ₁₂ – Z
L	Н	Н	L	Н	Y ₁₃ – Z
L	Н	Н	Н	L	Y ₁₄ – Z
L	Н	Н	Н	Н	Y ₁₅ – Z
Н	Х	Х	Х	Х	None

FUNCTIONAL DIAGRAM

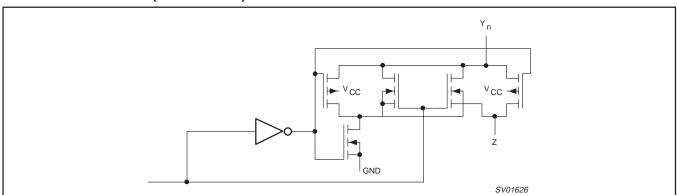


NOTES:

H = HIGH voltage level L = LOW voltage level

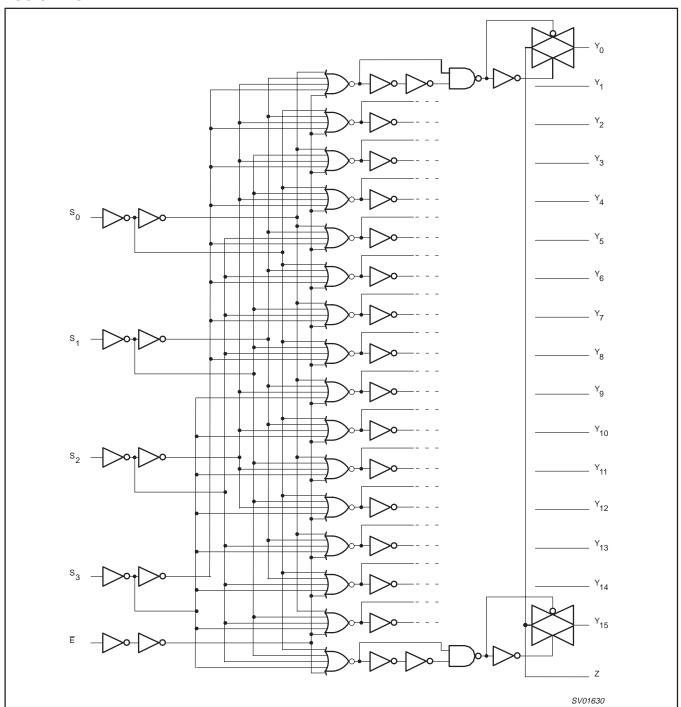
X = don't care

SCHEMATIC DIAGRAM (ONE SWITCH)



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LOGIC DIAGRAM



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ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
± I _{IK}	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5 \text{ V}$	20	mA
± I _{SK}	DC switch diode current	$V_S < -0.5 \text{ or } V_S > V_{CC} + 0.5 \text{ V}$	20	mA
±IS	DC switch current	$-0.5 \text{ V} < \text{V}_{\text{S}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	25	mA
T _{stg}	Storage temperature range		-65 to +150	°C
Р _{ТОТ}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1 and Figure 5	1.0	3.3	6.0	V
V _I	Input voltage		0	_	V _{CC}	V
Vo	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$ $V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 2.7 \text{ V to } 6.0 \text{ V}$	 - -	- - -	500 200 100	ns/V

NOTE:

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{1.} The LV is guaranteed to function down to $V_{CC} = 1.0 \text{V}$ (input levels GND or V_{CC}); DC characteristics are guaranteed from $V_{CC} = 1.2 \text{V}$ to $V_{CC} = 6.0 \text{V}$.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, voltages are referenced to GND (ground = 0 V)

						LIMITS			1
SYMBOL	PARAMETER	TEST CO	NDITIONS	-4	0°C to +8	5°C	-40°C t	o +125°C	UNIT
			İ	MIN	TYP ¹	MAX	MIN	MAX	7
		V _{CC} = 1.2 V		0.9	1		0.9		
	l <u>-</u>	V _{CC} = 2.0 V		1.4	1		1.4		1
V_{IH}	HIGH level Input voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$		2.0	1		2.0		V
	Voltage	V _{CC} = 4.5 V		3.15	1		3.15		1
		V _{CC} = 6.0 V		4.20	1		4.20		7
		V _{CC} = 1.2 V			1	0.3		0.3	
		V _{CC} = 2.0 V			1	0.6		0.6	1
V_{IL}	LOW level Input voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$			1	0.8		0.8	V
	Voltage	V _{CC} = 4.5 V			1	1.35		1.35	1
		V _{CC} = 6.0 V			1	1.80		1.80	1
	Input leakage	$V_{CC} = 3.6$	\/ \/ == CND		1	1.0		1.0	
±I ₁	current	$V_{CC} = 6.0$	$V_I = V_{CC}$ or GND			2.0		2.0	μA
	Analog switch	V _{CC} = 3.6	$V_I = V_{IH}$ or V_{IL}			1.0		1.0	
±IS	OFF-state current per channel	V _{CC} = 6.0	IV _S I = V _{CC} - GND (See Figure 2)			2.0		2.0	μΑ
±I -	Analog switch	V _{CC} = 3.6	$V_I = V_{IH} \text{ or } V_{IL}$			1.0		1.0	μА
±IS	ON-state current	V _{CC} = 6.0	IV _S I = V _{CC} - GND (See Figure 3)			2.0		2.0	
1	Quiescent supply	V _{CC} = 3.6 V	$V_I = V_{CC}$ or GND			20.0		40	μΑ
lcc	current	V _{CC} = 6.0 V	$V_{IS} = GND \text{ or } V_{CC};$ $V_{OS} = V_{CC} \text{ or } GND$			40.0		80	
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$	$V_{I} = V_{CC} - 0.6 \text{ V}$			500		850	μА
		V _{CC} = 1.2 V	$V_I = V_{IH} \text{ or } V_{IL};$ $I_S = 100 \mu A;$ $V_{IS} = V_{CC} \text{ to GND}$						
	ON-resistance	V _{CC} = 2.0 V			145	325		375	7
R_{ON}	(peak)	V _{CC} = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL}$		90	200		235	Ω
		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$I_S = 1000 \mu A;$		80	180		210	7
		V _{CC} = 4.5 V	$V_{IS} = V_{CC}$ to GND		60	135		160	7
		V _{CC} = 6.0 V	1 1		55	125		145	7
		V _{CC} = 1.2 V	$V_I = V_{IH} \text{ or } V_{IL};$ $I_S = 100 \mu A;$ $V_{IS} = GND$		225				
	ON-resistance	V _{CC} = 2.0 V			110	235		270	7
R_{ON}	(rail)	V _{CC} = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL}$		70	145		165	Ω
		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$I_S = 1000 \mu A;$		60	130		150	7
		V _{CC} = 4.5 V	V _{IS} = GND		45	100		115	┪
		V _{CC} = 6.0 V	7 1		40	85		100	7

3. R_{ON} (MAX) data is preliminary.

All typical values are measured at T_{amb} = 25°C.
 At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

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DC ELECTRICAL CHARACTERISTICS (Continued)

						LIMITS			
SYMBOL	PARAMETER	TEST COM	-40°C to +85°C			-40°C to	+125°C	דואט	
			MIN	TYP ¹	MAX	MIN	MAX	1 !	
		V _{CC} = 1.2 V	$V_I = V_{IH} \text{ or } V_{IL};$ $I_S = 100 \mu A;$ $V_{IS} = V_{CC}$		250				Ω
	R _{ON} ON-resistance (rail)	V _{CC} = 2.0 V			120	320		370	
R _{ON}		$V_{CC} = 2.7 \text{ V}$	$V_I = V_{IH}$ or V_{IL} ;		75	195		225] !
		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$I_S = 1000 \mu A;$		70	175		205	Ω
		V _{CC} = 4.5 V	$V_{IS} = V_{CC}$		50	130		150	1 !
		V _{CC} = 6.0 V	1		45	120		135	1 !
		V _{CC} = 1.2 V							
	Maximum variation	V _{CC} = 2.0 V	1		5				1 !
ΔR _{ON}	of ON-resistance	$V_{CC} = 2.7 \text{ V}$	$V_I = V_{IH}$ or V_{IL} ; $V_{IS} = V_{CC}$ to GND		4				$\bigcup_{\Omega} \mid$
_ ANON	between any two	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$V_{IS} = V_{CC}$ to GND		4				52
	channoic L	V _{CC} = 4.5 V	1		3				
		$V_{CC} = 6.0 \text{ V}$			2				

All typical values are measured at T_{amb} = 25°C.
 At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

^{3.} R_{ON} (MAX) data is preliminary.

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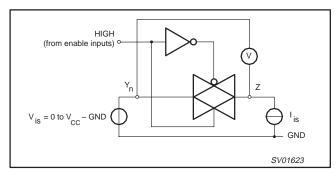


Figure 1. Test circuit for measuring ON-resistance (R_{ON}).

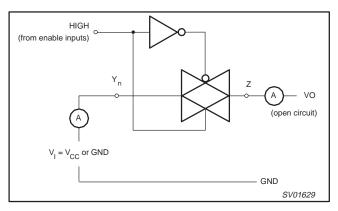


Figure 3. Test circuit for measuring ON-state current.

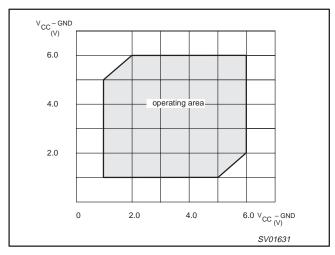


Figure 5. Guaranteed operating area as a function of the supply voltages.

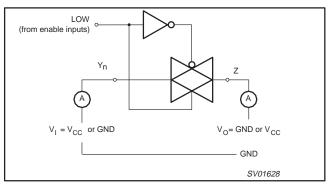


Figure 2. Test circuit for measuring OFF-state current.

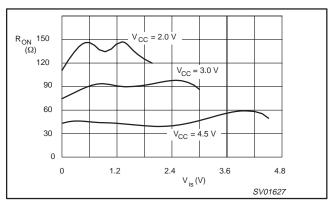


Figure 4. Typical ON-resistance (R_{on}) as a function of input voltage (V_{is} for V_{is} = 0 to V_{CC} – GND.

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AC CHARACTERISTICS

 $GND = 0 \text{ V; } t_r = t_f \leq 2.5 \text{ns; } C_L = 50 \text{pF}$

		CONDIT	ION			LIMITS			
SYMBOL	PARAMETER		ION	_	40 to +85 °	Č.	-40 to	+125 °C	UNIT
		V _{CC} (V)	OTHER	MIN	TYP ¹	MAX	MIN	MAX	0
		1.2			30				
		2.0			10	19		24	
t _{PHL} /t _{PLH}	Propagation delay	2.7	$R_L = \infty;$ $C_L = 50 \text{ pF}$		8	14		18	ns
PHL/PLH	V _{is} to V _{os} Z to Y _n	3.0 to 3.6	Figure 13		6 ²	11		14	113
		4.5			5	9		12	
		6.0			4	7		9	
		1.2			45				
		2.0			15	31		36	
tt	Propagation delay	2.7	$R_L = \infty;$ $C_L = 50 \text{ pF}$		11	23		26	ns
t _{PHL} /t _{PLH}	V _{is} to V _{os} Y _n to Z	3.0 to 3.6	Figure 13		92	18		21	115
		4.5	1 iguro 10		8	15		18	
		6.0			6	12		14	
		1.2			145				
		2.0	$R_L = 1k\Omega$		49	94		112	ns
+ /+	Turn-on time	2.7	$C_L = 50 \text{ pF}$		36	69		86	
t _{PZH} /t _{PZL}	$\overline{E}_{to} Y_n$	3.0 to 3.6	Figures 14		28 ²	55		66	
		4.5	and 15		25	47		56	
		6.0			19	38		43	
		1.2			160				
		2.0	$R_1 = 1k\Omega$		54	102		122	
+ /+	Turn-on time	2.7	$C_L = 50 \text{ pF}$		40	75		94	20
t _{PZH} /t _{PZL}	Z to Y _n	3.0 to 3.6	Figures 14		30 ²	60		72	ns
		4.5	and 15		27	51		61	
		6.0			21	39		47	
		1.2			125				
		2.0	$R_L = 1k\Omega$		43	80		95	
+/+	Turn-off time	2.7	$C_L = 50 \text{ pF}$		33	59		71	20
t _{PHZ} /t _{PLZ}	$\overline{E}_{to} Y_n$	3.0 to 3.6	Figures 14		26 ²	48		57	ns
		4.5	and 15		23	41		49	
		6.0			18	32		38	
		1.2			140				
		2.0	$R_L = 1k\Omega$		49	90		109	
+ / +	Turn-off time	2.7	$C_{L} = 50 pF$		37	67		81	no
t _{PHZ} /t _{PLZ}	Sn to Y _n	3.0 to 3.6	Figures 14		29 ²	54		65	ns ns
		4.5	and 15		26	46		56	
		6.0	\neg		20	36		43	

NOTES:

Unless otherwise stated, all typical values are measured at T_{amb} = 25°C
 Typical values are measured at V_{CC} = 3.3 V.

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AC CHARACTERISTICS (Continued)

GND = 0 V; $t_r = t_f \le 2.5 \text{ns}$; $C_L = 50 \text{pF}$

		CONDITIO	N		40 to +85 °	C	-40 to -	⊦125 °C	
SYMBOL	PARAMETER	V _{CC} (V)	OTHER	MIN	TYP ¹	MAX	MIN	MAX	UNIT
		1.2			145				
		2.0	$R_L = 1k\Omega$		51	93		110	
t _{PZH} /t _{PZL}	Turn-on time	2.7	$C_L = 50 pF$		39	70		83	ns
'PZH''PZL	E to Z	3.0 to 3.6	Figures 14		29 ²	56		66	113
		4.5	and 15		26	48		56	
		6.0	1		20	36		43	
		1.2			170				
		2.0	$R_L = 1k\Omega$		58	109		131	
t _{PZH} /t _{PZL}	Turn-on time S _n to Y _n	2.7	$C_{L} = 50 pF$		42	80		96	ns
IPZH/IPZL		3.0 to 3.6	Figures 14		32 ²	64		77	
		4.5	and 15		29	54		65	
		6.0	1		21	42		50	
		1.2			145				ns
		2.0	$R_L = 1k\Omega$		51	93		110	
t _{PHZ} /t _{PLZ}	Turn-off time	2.7	$C_L = 50 pF$		38	69		82	
PHZ/PLZ	E to Z	3.0 to 3.6	Figures 14		30 ²	56		66	
		4.5	and 15		29	48		56	
		6.0	1		21	37		44	
		1.2			160				
		2.0	$R_L = 1k\Omega$		56	104		124	
+ /+	Turn-off time	2.7	$C_L = 50 \text{ pF}$		42	77		92	ns
t _{PHZ} /t _{PLZ}	S_n to Y_n	3.0 to 3.6	Figures 14		32 ²	62		74	
		4.5	and 15		29	53		61	
		6.0]		23	41		49	

NOTES:

Unless otherwise stated, all typical values are measured at T_{amb} = 25°C
 Typical values are measured at V_{CC} = 3.3 V.

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ADDITIONAL AC CHARACTERISTICS

Recommended conditions and typical values GND = 0 V; $t_r = t_f \le 2.5 ns$

SYMBOL	PARAMETER	TYP.	UNIT	V _{CC} (V)	V _{is(p-p)} (V)	CONDITIONS
	Sine-wave distortion f = 1 kHz	0.80 0.40	%	3.0 6.0	2.75 5.50	$R_L = 10 \text{ k}\Omega; C_L = 50 \text{ pf}$ Figures 10 and 11
	Sine-wave distortion f = 10 kHz	2.40 1.20	%	3.0 6.0	2.75 5.50	$R_L = 10 \text{ k}\Omega; C_L = 50 \text{ pf}$ Figures 10 and 11
	Switch "OFF" signal feed through	-50 -50	dB	3.0 6.0	Note 1	$R_L = 600 \Omega$; $C_L = 50 \text{ pf}$; $f = 1 \text{ MHz}$ Figures 6 and 12
	Crosstalk between any two switches/multiplexers	-60 -60	dB	3.0 6.0	Note 1	$R_L = 600 \Omega$; $C_L = 50 \text{ pf}$; $f = 1 \text{ MHz}$ Figure 8
V _(p-p)	Crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 120	mV	3.0 6.0		$R_L = 600 \ \Omega$; $C_L = 50 \ pf$; $f = 1 \ MHz$ (S_n or E , square wave between V_{CC} and $GND \ t_r = t_f = 6 \ ns$) Figure 9
f _{max}	Minimum frequency response (–3 dB)	180 200	MHz	3.0 6.0	Note 2	R_L = 50 Ω; C_L = 50 pF Figures 7 and 10
Cs	Maximum switch capacitance	5	pf			

GENERAL NOTES:

 V_{is} is the input voltage at nY or Z terminal, whichever is assigned as an input.

V_{OS} is the output voltage at nY or Z terminal, whichever is assigned as an output.

NOTES:

1. Adjust input voltage V_{is} is 0 dBm level (0 dBm = 1 mW into 600 Ω).

2. Adjust input voltage V_{is} is 0 dBm level at V_{OS} for 1 MHz (0 dBm = 1 mW into 50 Ω).

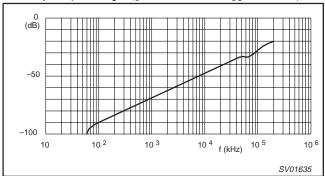


Figure 6. Typical switch "OFF" signal feed-through as a function of frequency.

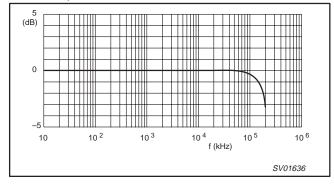


Figure 7. Typical frequency response.

NOTES TO FIGURES 6 AND 7:

Test conditions: V_{CC} = 3.0 V; GND = 0 V; R_L = 50 Ω ; R_{SOURCE} = 1k Ω .

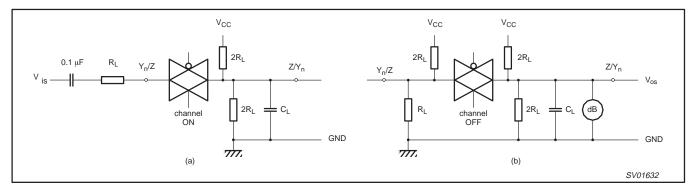


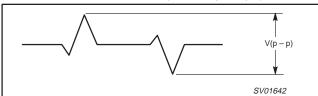
Figure 8. Test circuit for measuring crosstalk between any two switches.
(a) channel ON condition; (b) channel OFF condition.

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NOTE TO FIGURE 9:

The crosstalk is defined as follows (oscilloscope output):



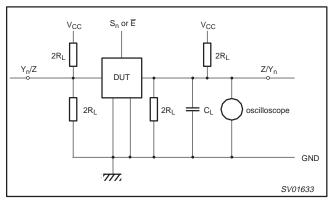


Figure 9. Test circuit for measuring crosstalk between control and any switch.

NOTE TO FIGURE 10:

Adjust input voltage to obtain 0 dBm at V_{OS} when F_{in} = 1 MHz. After set-up frequency of f_{in} is increased to obtain a reading of –3 dB at V_{OS} .

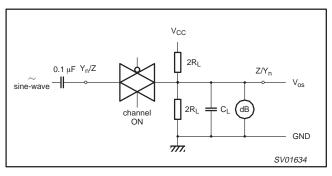


Figure 10. Test circuit for measuring minimum frequency response.

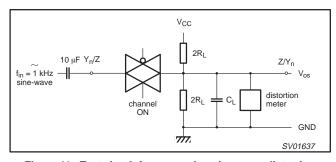


Figure 11. Test circuit for measuring sine-wave distortion.

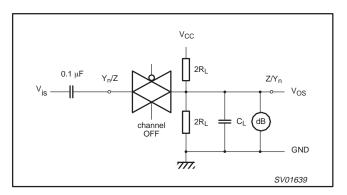


Figure 12. Test circuit for measuring switch "OFF" signal feed-through.

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WAVEFORMS

 $V_{M} = 1.5 \text{ V at } 2.7 \text{ V} \le V_{CC} \le 3.6 \text{ V}$

 $V_{M} = 0.5 \times V_{CC}$ at 2.7 V > $V_{CC} > 3.6$ V

 $V_{\mbox{OL}}$ and $V_{\mbox{OH}}$ are the typical output voltage drop that occur with the output load

 $\begin{array}{l} \text{V}_{X} = \text{V}_{OL} + 0.3 \text{ V at } 2.7 \text{ V} \leq \text{V}_{CC} \leq 3.6 \text{ V} \\ \text{V}_{X} = \text{V}_{OL} + 0.1 \times \text{V}_{CC} \text{ at } 2.7 \text{ V} > \text{V}_{CC} > 3.6 \text{ V} \\ \text{V}_{Y} = \text{V}_{OH} - 0.3 \text{ V at } 2.7 \text{ V} \leq \text{V}_{CC} \leq 3.6 \text{ V} \\ \text{V}_{Y} = \text{V}_{OH} - 0.1 \times \text{V}_{CC} \text{ at } 2.7 \text{ V} > \text{V}_{CC} > 3.6 \text{ V} \end{array}$

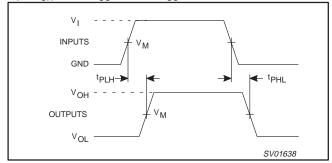


Figure 13. Input (V_{is}) to output (V_{os}) propagation delays.

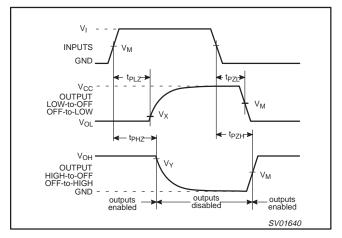


Figure 14. Turn-on and turn-off times for the inputs (S_n, \overline{E}) to the output (V_{os}) .

TEST CIRCUIT

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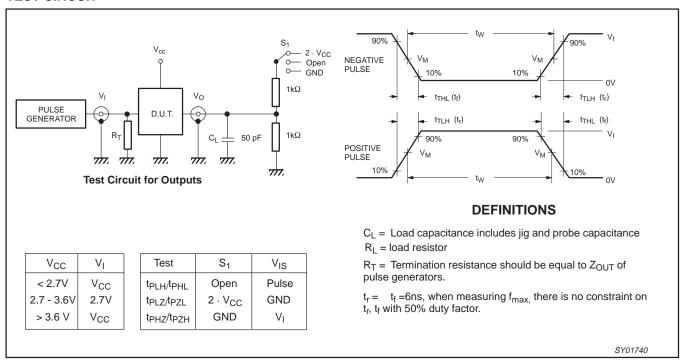


Figure 15. Load circuitry for switching times.

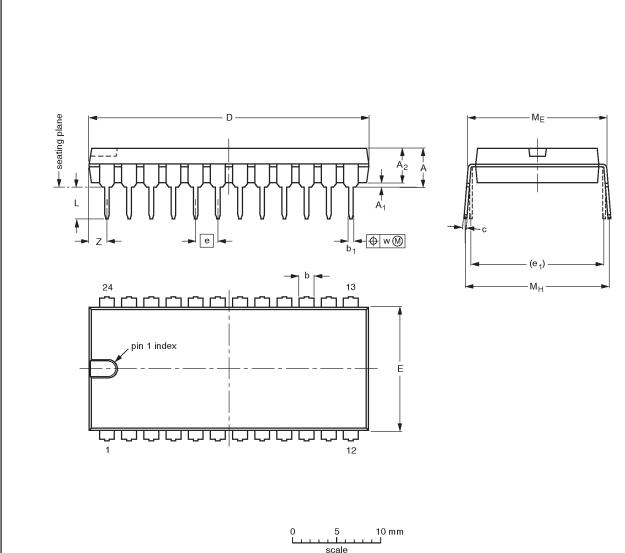
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DIP24: plastic dual in-line package; 24 leads (600 mil)

SOT101-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	5.1	0.51	4.0	1.7 1.3	0.53 0.38	0.32 0.23	32.0 31.4	14.1 13.7	2.54	15.24	3.9 3.4	15.80 15.24	17.15 15.90	0.25	2.2
inches	0.20	0.020	0.16	0.066 0.051	0.021 0.015	0.013 0.009	1.26 1.24	0.56 0.54	0.10	0.60	0.15 0.13	0.62 0.60	0.68 0.63	0.01	0.087

Note

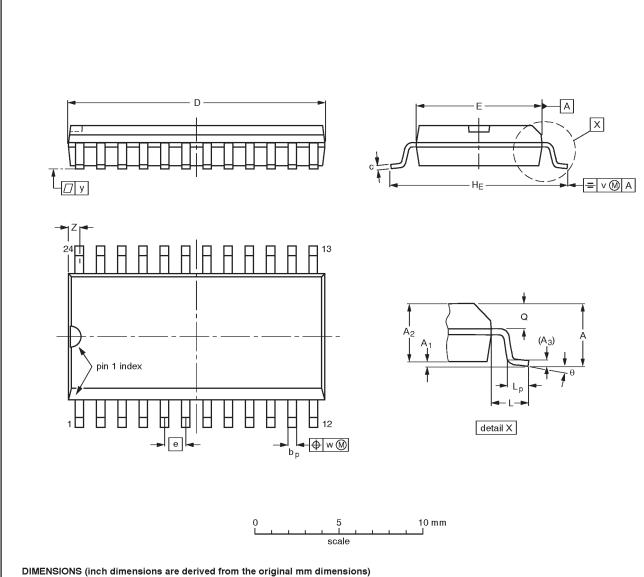
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT101-1	051G02	MO-015AD			92-11-17 95-01-23

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plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



UNIT	A max.	Α1	A ₂	A ₃	рb	С	D ⁽¹⁾	E ⁽¹⁾	Φ	HE	٦	Lp	Ø	v	v	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	15.6 15.2	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.61 0.60	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

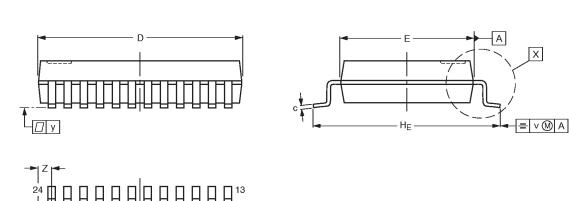
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

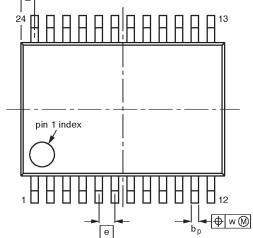
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT137-1	075E05	MS-013AD				-92-11-17 95-01-24	

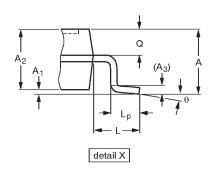
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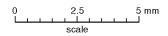
SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1









DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	8.4 8.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.8 0.4	8° 0°

Note

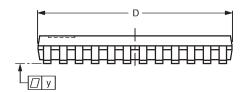
1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

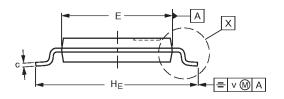
OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	RSION IEC JEDEO		EIAJ	PROJECTION	ISSUE DATE	
SOT340-1		MO-150AG			93-09-08 95-02-04	

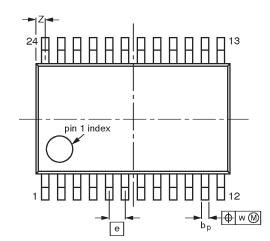
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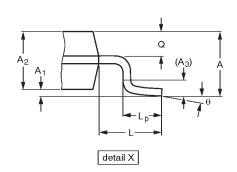
TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1











DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT355-1		MO-153AD				-93-06-16 95-02-04

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NOTES

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